## DECLARATION FOR PATENT APPLICATION AND APPOINTMENT OF ATTORNEY

As a below named inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name; I believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention (Design, if applicable) entitled:

## Group III nitrides semiconductor device and manufacturing process

or  $\square$  was filed on:

the specification of which (check one):

is attached hereto;

I hereby s mendment(s) referred to a Regulations, §1.56. I hereby sted below and have also in	was amended on: tate that I have reviewed a bove. I acknowledge the claim foreign priority bene-	duty to disclose informat fits under Title 35, United	s of the above-id ion which is ma States Code §11:	lication Number; lentified specification, including terial to patentability as defing 9 of any foreign application(s) tate having a filing date befor	ned in <i>Title 37, Code</i> of for patent or inventor's	of Federal	
riority is claimed.  PRIOR FOREIGN APPLICATION(S)							
Number		Country		Day/Month/Year I		No	
092129057		Taiwan, R.O.C.		20/10/2003	х		
	☐ Additio	nal Priority Application	n(s) Listed on F	Following Page(s)			
I HEREBY CLAIM	THE BENEFIT UNDER T	TTLE 35 U.S. CODE § 11	9(E) OF ANY U	S. PROVISIONAL APPLICA	TIONS LISTED BELO	W.	
	Application Numb	ег		Day/Month/Year Filed			
n the manner provided by the s defined in <i>Title 37, Code</i> atternational filing date of this	e first paragraph of Title 35, of F ederal R egulations, § s application:	United States Code, §112	, 1 acknowledge	f this application is not disclose the duty to disclose information of filing date of the prior appl	n which is material to prications) and the nation	atentability	
Application	n Number	Filing Date	· ·	Status - Patented, Pending or Abandoned			
	□ Additional l	US/PCT Priority Appli		Fallania - Banda			
rue; and further that these st oth, under Section 1001 of ssued thereon.	nat all statements made here atements were made with the Title 18 of the United State	ein of my own knowledge he knowledge that willful es Code and that such wil (We) hereby appoint as m	are true and that false statements a lful false stateme	all statements made on informand the like so made are punisents may jeopardize the validition with full powers of substitution	shable by fine or impris- ty of the application or	onment, or any patent	
	, E	Bruce H. Troxell.	Reg. No.	26,592			
natter related to the preparati	my (our) attorneys to acce ion, examination, grant and til I (we) or my (our) assign	maintenance of this appli-	cation, any contin	IP Endeavor Corporationuation, continuation-in-part or		arding any n, and any	
END CORRESPONDENCI	5205 LEES	LAW OFFICE PLLC BURG PIKE, SUITE 140 URCH, VA. 22041	4	TELEPHONE CALLS TO: BRUCE H. TROXELL (703) 575-2711			
FULL NAME OF FIRST OR SOLE	INVENTOR Tsai,	Fzong-Liang	CITIZENSHIP	Taiwan, R.O.C.			
RESIDENCE ADDRESS 3F, No.130, Lane 160, Gaocuei Rd., Hsinchu City 300, Taiwan, R.O.C.			POST OFFICE ADDRESS IS THE SAME AS RESIDENCE ADDRESS UNLESS OTHERWISE SHOWN BELOW				
DATE	Nov.24, 2003		SIGNATURE	Trong - Long	Sai		
	🛭 See fo	llowing page(s) for a	dditional join	t inventors.			

## CONTINUATION OF DECLARATION FOR PATENT APPLICATION AND APPOINTMENT OF ATTORNEY

Page \_\_\_\_\_2

PRIOR FOREIGN APPLICATION(S)										
Number Country			Day/Month/Year Filed	Yes	No					
092129057	Taiwan, R.O.C.		20/10/2003	х						
PRIOR PROVISIONAL APPLICATIONS 35 U.S. CODE § 119(E)										
Application Number	Filing Date		Status - Patented, Pending or Abandoned							
PRIOR U.S	. OR PCT INTERNATIONA	L APPLICATIONS	(35 U.S. CODI§ 120)							
Application Number	Filing Date	Status - Patented, Pending or Abandoned								
				-						
Full Name of Joint Inventor Chang, Chih-Sung		Citizenship	Taiwan, R.O.C.							
Full Name of Joint Inventor Chang, Chih-Sung  Residence Address No.1, Alley 51, Lane 400, Minghu Rd.,		Post Office Address Is the Same as Residence Address Unless Otherwise Shown below								
Hsinchu City 300, Tai										
Date Nov. 24, 2003		Signature (hih - Sung Chang)								
			, , , , , , , , , , , , , , , , , , ,							
Full Name of Joint Inventor	Citizenship									
Residence Address	Post Office Address Is the Same as Residence Address Unless Otherwise Shown									
		below								
Date .		Signature .								
Full Name of Joint Inventor	Citizenship									
Residence Address	Post Office Address Is the Same as Residence Address Unless Otherwise Shown below									
Date	Signature									
Full Name of Joint Inventor	Citizenship									
Residence Address	Post Office Address Is the Same as Residence Address Unless Otherwise Shown below									
Date	Signature									